

List of figures

Figure No.	Figure Caption	Page No.
Figure 1.1	Large area based application of CPs and its composites [2].	2
Figure 1.2	(i) Chemical structure of CPs, (ii) conductivity comparison of undoped (pristine) and doped polymers [7].	4
Figure 1.3	(a) Generation of polaron, bipolaron and bipolaron bands as a result of doping level in various CPs (b) Formation of neutral, positive and negatively charged soliton, (c) formation of two charged solitons on a chain of trans-PA [6].	4
Figure 1.4	(a) Schematic representation of the semi-crystalline structure of P3HT (b) High resolution-TEM micrograph showing the packing of P3HT chains, (inset: SAED pattern) [35].	13
Figure 1.5	Arrangement of polymer backbone from solution (bulk) to ordered array.	15
Figure 1.6	(a) TEM image of AgNP superlattice, histogram (PSD= 4.1 ± 0.23 nm) (b) HR-TEM (interparticle distance=1.51 nm) (c) 2-D Fourier transform spectrum of (b) [52].	15
Figure 1.7	Deposition type on hydrophilic and hydrophobic substrates for transfer of Langmuir monolayers: (a) Z-type, (e) Y-type, (f) X-type.	19
Figure 1.8	Various steps involved in Langmuir technique. Step 1: A-C) solvent spreading, Step 2: Barrier compression, Step 3: Substrate stamping (Schaefer style), Step 4: Substrate lifting.	21
Figure 1.9	SP vs. area (π -A) isotherm depicting various monolayer phase transitions.	22
Figure 1.10	Energy level diagram of metal-semiconductor (n-type) interface (a) before and (b) after the contact.	26
Figure 1.11	Energy level diagram of metal-semiconductor (p-type) interface (a) before and (b) after the contact.	27
Figure 1.12	Energy level diagram of metal-semiconductor interface for ohmic behaviour (a) before and (b) after the contact.	28

Figure 1.13	Oxidative polymerization mechanism of indole.	31
Figure 2.1	Reaction scheme for the synthesis of PIn.	37
Figure 2.2	Experimental setup for electrochemical synthesis of PIn.	38
Figure 2.3	Schematic representation of interfacial polymerization of 5-AIn at aqueous/organic solvent system. The top phase is an aqueous solution of APS and bottom phase is monomer/Chloroform solution.	39
Figure 2.4	Schematic representation of hydrothermal synthesis of MoS ₂ nanosheets, their exfoliation, and MoS ₂ -PIn nanocomposite formation.	40
Figure 2.5	Biphasic system with chloroform at bottom containing various DDAB concentration labelled as (1) 5, (2) 10, (3) 25, (4) 50 and (5) 75 mM and upper layer containing hydrosol (a) Before phase transfer (b) After phase transfer.	43
Figure 2.6	Photograph of LB film deposition system.	44
Figure 2.7	Photograph of Nuclear Magnetic Resonance (NMR) spectrometer and its basic working principle.	45
Figure 2.8	Electronic transitions in a molecule.	46
Figure 2.9	Basic instrumentation of UV-Vis spectrometer.	47
Figure 2.10	(a) A simple schematic diagram of the FT-IR spectrometer (b) Photograph of FT-IR spectrometer.	47
Figure 2.11	Physical process involved in XPS.	49
Figure 2.12	Schematic representation of the experimental setup of CV.	50
Figure 2.13	Photograph of our SEM and HR-SEM.	52
Figure 2.14	(a) Photograph of TEM (b) Layout of optical component of TEM instrument.	52
Figure 2.15	A simple schematic diagram of the AFM.	53
Figure 2.16	Schematic diagram of Thermal Evaporating vacuum system.	55
Figure 2.17	(a) Schematic diagram of ITO/Semiconductor LB (or LS) film/Al sandwiched structure, and (b) Photograph of sourcemeter.	56
Figure 3.1	(a) ¹ H-NMR spectrum and (b) FT-IR spectrum of electrochemically synthesized PIn.	61

Figure 3.2	FAB Mass spectrum of electrochemically synthesized PIn.	61
Figure 3.3	Pressure vs. area (π -A) isotherm of PIn at room temperature (marked points display different pressures 20, 30 and 40 mN/m under study). Inset shows photograph of PIn solution prepared for LB study.	62
Figure 3.4	Tapping mode AFM and SEM images of monolayer LB film of PIn at different deposition pressures (as marked in isotherm) (a & b) @ 20 mN/m, (c & d) @ 30 mN/m, (e & f) @ 40 mN/m respectively. Each inset shows the magnified image encircled region	64
Figure 3.5	(a) SEM image of single layer LB film of PIn. Inset shows the magnified image encircled region (b) AFM image of single layer LB film of PIn.	65
Figure 3.6	Topographic AFM 3D images of monolayer PIn LB film deposited at different SP (a) 20 mN/m, (b) 30 mN/m, (c) 40 mN/m respectively.	65
Figure 3.7	Schematic representation of plausible arrangement of PIn molecules onto water subphase at different SP (20, 30 and 40 mN/m).	67
Figure 3.8	(a) UV-Vis absorption spectra of PIn (solution) and LB film of PIn with inset depicting its band gap.(b) Raman spectra of PIn (Powder) synthesized electrochemically and PIn LB film (monolayer and 5 layers), respectively.	67
Figure 3.9	(a) J-V characteristics of LB film of PIn single layer (1 L), 3 layers (3 L), and 5 layers (5 L) respectively (b) semilog plot of single layer, 3 layers and 5 layers.	73
Figure 4.1	¹ H-NMR spectra of (a) 5-AIn (b) 5-APIIn.	79
Figure 4.2	FT-IR spectra of (a) 5-AIn (b) 5-APIIn.	81
Figure 4.3	Plausible mechanism of polymerization of 5-AIn.	83
Figure 4.4	UV-visible spectrum of (a) 5-AIn (b) 5-APIIn (Inset shows optical band gap of 5-APIIn)	84
Figure 4.5	Gel permeation chromatogram of 5-APIIn.	85
Figure 4.6	XRD pattern of 5-APIIn.	85

Figure 4.7	SEM images of 5-APIIn formed at the interface after (a) 3 min, (b) 5 min, (c) 15 min, (d) magnified form of image (c), (e) 60 min and (f) after 24h.	86
Figure 4.8	TGA and DTA curves of 5-AIn (a & a') and 5-APIIn (b & b') respectively.	88
Figure 4.9	CV of (a) bare Au electrode (b) 5-APIIn/Au. The inset shows an enlarged view of similar CV plot.	89
Figure 4.10	CV of (a) bare Au electrode and 5-APIIn/Au in presence of 0.5 M H ₂ SO ₄ at scan rate (b) 20 mVs ⁻¹ , (c) 50 mVs ⁻¹ and (d) 100 mV s ⁻¹ .	90
Figure 4.11	Schematic representation of redox recyclability behavior of 5-APIIn in 0.5M H ₂ SO ₄ .	91
Figure 4.12	EIS of (a) bare Au electrode, (b) 5-APIIn/Au. (inset: EIS data fitted by ZSimp software for bare Au electrode and 5-APIIn/Au with their electrical equivalent circuit.)	92
Figure 4.13	Electron distribution for the 5-APIIn (a) HOMO and (b) LUMO energy levels obtained at the wB97XD/6-31G* level of theory in gas phase. Here blue, gray and white balls represent N, C and H-atoms respectively.	92
Figure 4.14	Pressure-area (π -A) isotherm of 5-APIIn depicting various regions I, II, III, IV (inset shows 5-APIIn dispersion)	94
Figure 4.15	SEM images 5-APIIn LS film deposited at different pressures (a) 35, (b) 45, (c) magnified image of b, (d) 55 mN/m, and (e) multilayer (5L) LS film lifted at 45 mN/m.	97
Figure 4.16	Tapping-mode AFM image of 5-APIIn fabricated at optimum pressure (45 mN/m) via LS method (a) 2D (b) 3D (c) and (d) horizontal and vertical surface profile.	97
Figure 4.17	Raman spectra of (a) 5-APIIn LS film and (b) 5-APIIn powder (bulk).	98
Figure 4.18	Pictorial representation depicting the 5-APIIn dispersion spread over water subphase (a) before and (b) after compression upto 45 mN/m and its LS film fabrication.	99
Figure 4.19	(a) log J vs. V plot and (b) log J vs. log V plot of sandwiched	99

	structure Al/APIn LS film/ITO.	
Figure 5.1	Characterizations of MoS ₂ nanosheets synthesized via hydrothermal process (a) TEM (inset showing SAED pattern) (b) HRTEM image, (c) intensity profile graph depicting interlayer distance, (d) EDS elemental analysis, (e) XRD pattern.	109
Figure 5.2	(a) HAADF-STEM, (b) TEM image and element mapping images of MoS ₂ (c) S, (d) Mo.	109
Figure 5.3	(a) UV-vis and (b) vibrational spectroscopy of (i) MoS ₂ nanosheets, (ii) PIn and (iii) MoS ₂ -PIn composite.	110
Figure 5.4	(a) XRD pattern and (b) TGA of (i) PIn and (ii) MoS ₂ -PIn nanocomposite (bulk).	112
Figure 5.5	TEM micrographs of drop casted MoS ₂ -PIn nanocomposite at different scale bars (a) 200 nm (b) 50 nm.	113
Figure 5.6	(a) HAADF-STEM and (b) element mapping images of MoS ₂ -PIn nanocomposite (bulk drop casted): (c) C, (d) N, (e) S, (f) Mo.	113
Figure 5.7	CV curves of (a) GCE, (b) MoS ₂ /GCE, (c) PIn/GCE, (d) MoS ₂ -PIn-1/GCE, and (e) MoS ₂ -PIn-2/GCE (f) MoS ₂ -PIn-3/GCE in a 5 mM [Fe(CN) ₆] ^{3-/4-} mixture (1:1); 0.1 M KCl (Scan rate 20 mVs ⁻¹).	114
Figure 5.8	TEM micrographs of LS films of (a) MoS ₂ -PIn-1 and (b) MoS ₂ -PIn-3 (dark patches pointed with arrows represent MoS ₂).	114
Figure 5.9	Pressure vs. Area (π -A) isotherm of (a) PIn and (b) MoS ₂ -PIn nanocomposite.	117
Figure 5.10	Schematic representation of assembly of MoS ₂ -PIn on water subphase initially, after barrier compression and LS film fabrication.	117
Figure 5.11	TEM micrographs of LS films of (a,b) PIn and (c,d) MoS ₂ -PIn.	120

Figure 5.12	(a) HAADF-STEM and (b) element mapping images of MoS ₂ -PIn LS film: (c) C, (d) N, (e) S, (f) Mo.	120
Figure 5.13	Tapping mode AFM and phase contrast images of LS films of (a,b) PIn and (c,d) MoS ₂ -PIn.	121
Figure 5.14	(a) Current density-voltage (J-V) measurement (b) Semi-log plot for 5 layered LS film fabricated Al/PIn/ITO (black curve) and Al/ MoS ₂ -PIn/ITO (red curve) device structure.	121
Figure 6.1	UV-vis spectra of (a) deionised water, (b) chloroform, (c) pure silver hydrosol, (d) supernatant aqueous phase (after phase transfer; shown in inset) and (e) chloroform subphase (after phase transfer; shown in inset).	130
Figure 6.2	FT-IR spectra of (a) pure DDAB (b) silver organosol.	131
Figure 6.3	XPS spectra of silver organosol.	131
Figure 6.4	XRD pattern of silver NPs in organic phase. Inset shows amplified diffraction pattern corresponding to (111), (200), (220) and (311) planes of fcc silver.	132
Figure 6.5	TEM image of (a) silver hydrosol (inset: SAED pattern) (b) silver organosol (inset: SAED pattern)	134
Figure 6.6	TEM images of silver colloid in organic phase (inset: histogram depicting PSD) with varying DDAB concentration namely (a) 5 mM (b) 10 mM (c) 25 mM (d) 50 mM (e) 75 mM and (f) plausible structure for DDAB acting as AgNP stabilizer.	134
Figure 6.7	Trend of increasing median particle dimension (diameter) and the corresponding width of distribution represented as error bars.	137
Figure 6.8	(a) UV-Vis spectra of (i) organosol (ii) PIn, (iii) Ag-PIn, and (b) FT-IR spectra of (i) PIn and (ii) Ag-PIn.	138
Figure 6.9	Pressure vs area (π -A) isotherm for (a) PIn, and Ag-PIn along with schematic depicting the phenomena at various regions, (b) compression-expansion curve for PIn and Ag-PIn nanohybrid at SP=30 mN/m, (c) compression-relaxation phenomena at three different SPs (30, 40, and 50 mN/m) from	140

	different regions (II, III and IV) of the isotherm, (d) compression-relaxation cycle of Ag-PIn film.	
Figure 6.10	TEM micrograph of a single time lifted layer PIn LS film at 30 mN/m SP at (a) low magnification (inset: SAED) and (b) high magnification (inset: d-spacing).	143
Figure 6.11	(a) TEM image (inset: SAED pattern), (b) HAADF image and (c) elemental mapping of drop cast Ag-PIn nanohybrid film.	143
Figure 6.12	TEM micrograph of AgNP-PIn Langmuir film deposited at 40 mN/m at different magnification scale (a) 50 nm and (c) 20 nm; FT of Region 1 and 2.	144
Figure 6.13	GIWAXS 2D q plot of (a) PIn and (b) Ag-PIn LS film	145
Figure 6.14	Tapping mode atomic force micrographs of (a) PIn and (c) Ag-PIn Langmuir film deposited at 30 and 40 mN/m respectively with their corresponding (b) and (d) roughness distribution.	146
Figure 6.15	Phase contrast micrographs of (a) PIn and (c) Ag-PIn Langmuir film deposited at 30 and 40 mN/m respectively with their corresponding (b) and (d) grain segment.	147
Figure 6.16	(a) Film lifting method of type 1 and 2 for contact angle measurements of LS film of (b) 1-PIn, (c) 2-PIn and (d) Ag-PIn LS films, (e) and (f) Kelvin probe force micrographs of (b) and (d) LS films respectively.	148
Figure 6.17	UV-vis spectra of LS films (a) PIn and (b) Ag-PIn.	149
Figure 6.18	Raman spectra of (a) PIn and (b) Ag-PIn LS films (inset: SERs effect)	150
Figure 6.19	Current density-voltage (J-V and J-V ²) characteristics of 5L LS film of pristine PIn and Ag-PIn nanohybrid.	151
Figure 6.20	XPS spectra of C 1s and N 1s for (a & b) PIn LS film, (c & d) Ag-PIn LS film.	155
Figure 6.21	XPS spectra for the silver present in organosol and Ag-PIn LS film.	155
Figure 6.22	XPS spectra of Ag-PIn LS film: (a) N1s and (b) C1s spectrum. Peak positions are mentioned for the fitted	156

components.

Figure 6.23 Schematic representing the partial charge transfer from PIn to AgNPs resulting in lowering of BE, SERS phenomena and enhancement in charge transport property of Ag-PIn nanohybrid. **156**